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MUR1605CT MUR1630CT
MUR1610CT MUR1640CT
MUR1615CT MUR1650CT
MUR1620CT MUR1660CT

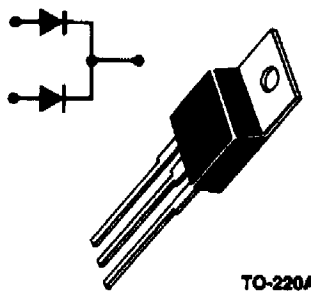
SWITCHMODE POWER RECTIFIERS

... designed for use in switching power supplies, inverters and as free wheeling diodes, these state-of-the-art devices have the following features:

- Ultrafast 35 and 60 Nanosecond Recovery Times
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy meets UL94, V_O @ ⅛"
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 Volts
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures

ULTRAFAST RECTIFIERS

8 AMPERES
50–600 VOLTS



TO-220AB
PLASTIC

MAXIMUM RATINGS

Rating	Symbol	MUR 1605CT	1610CT	1615CT	1620CT	1630CT	1640CT	1650CT	1660CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	150	200	300	400	500	600	Volts
Average Rectified Forward Current Per Leg Total Device, (Rated V_R), T_C = 150°C Total Device	$I_{F(AV)}$	8.0 16								Amps
Peak Repetitive Forward Current Per Diode Leg (Rated V_R, Square Wave, 20 kHz), T_C = 150°C	I_{FM}	16								Amps
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I_{FSM}	100								Amps
Operating Junction Temperature and Storage Temperature	T_J, T_{stg}	−65 to +175								°C

THERMAL CHARACTERISTICS, PER DIODE LEG

Maximum Thermal Resistance, Junction to Case	$R_{\theta JC}$	3.0	2.0	°C/W

ELECTRICAL CHARACTERISTICS, PER DIODE LEG

Maximum Instantaneous Forward Voltage (1) (i_F = 8.0 Amp, T_C = 150°C) (i_F = 8.0 Amp, T_C = 25°C)	v_F	0.895 0.975	1.00 1.30	1.20 1.50	Volts
Maximum Instantaneous Reverse Current (1) (Rated dc Voltage, T_C = 150°C) (Rated dc Voltage, T_C = 25°C)	i_R	250 5.0	500 10	500 10	μA
Maximum Reverse Recovery Time (I_F = 1.0 Amp, di/dt = 50 Amp/μs) (I_F = 0.5 Amp, i_R = 1.0 Amp, I_{REC} = 0.25 Amp)	t_{rr}	35 25	60 50		ns

(1)Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤2.0%

Quality Semi-Conductors